## Features

- $B V_{\text {CEO }}>-45 \mathrm{~V}$
- $\mathrm{I}_{\mathrm{C}}=-100 \mathrm{~mA}$ Collector Current
- Epitaxial Planar Die Construction
- Ultra-Small Surface Mount Package
- Complementary NPN Type: BC847AT, BT, CT
- Totally Lead-Free \& Fully RoHS Compliant (Notes 1 \& 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability


## Mechanical Data

- Case: SOT523
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.002 grams (Approximate)

SOT523


Top View


Device Symbol


Pin-Out Top View

## Ordering Information (Note 4)

| Product | Compliance | Marking | Reel Size (inches) | Tape Width (mm) | Quantity per Reel |
| :---: | :---: | :---: | :---: | :---: | :---: |
| BC857AT-7-F | AEC-Q101 | $3 V$ | 7 | 8 | 3,000 |
| BC857BT-7-F | AEC-Q101 | $3 W$ | 7 | 8 | 3,000 |
| BC857CT-7-F | AEC-Q101 | $3 G$ | 7 | 8 | 3,000 |

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) \& 2015/863/EU (RoHS 3) compliant.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain $<900 \mathrm{ppm}$ bromine, $<900 \mathrm{ppm}$ chlorine ( $<1500 \mathrm{ppm}$ total $\mathrm{Br}+\mathrm{Cl}$ ) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## Marking Information



XX = Product Type Marking Code
YM = Date Code Marking
$Y$ or $\bar{Y}=$ Year (ex: $F=2018$ )
$M$ or $\bar{M}=$ Month (ex: $9=$ September)

Date Code Key

| Year | 2018 | 2019 |  | 2020 | 2021 | 2022 | 2023 | 2024 | 2025 |  | 2026 |  | 2027 | 2028 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Code | F |  | G | H | 1 | J | K | L |  | M |  | N | O | P |
| Month |  | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug |  | Sep | Oct | Nov | Dec |
| Code |  | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 |  | 9 | O | N | D |

BC857AT, BT, CT
Absolute Maximum Ratings ( $@ \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Collector-Base Voltage | $\mathrm{V}_{\mathrm{CBO}}$ | -50 | V |
| Collector-Emitter Voltage | $\mathrm{V}_{\mathrm{CEO}}$ | -45 | V |
| Emitter-Base Voltage | $\mathrm{V}_{\text {EBO }}$ | -6 | V |
| Collector Current | $\mathrm{I}_{\mathrm{C}}$ | -100 | mA |

## Thermal Characteristics $\left(@ T_{\mathrm{A}}=+25^{\circ} \mathrm{C}\right.$, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Power Dissipation (Note 5) | $\mathrm{P}_{\mathrm{D}}$ | 150 | mW |
| Thermal Resistance, Junction to Ambient (Note 5) | $\mathrm{R}_{\theta J A}$ | 833 |  |
| Operating and Storage Temperature Range | $\mathrm{T}_{\mathrm{J},}, \mathrm{TSTG}_{\mathrm{ST}}$ | -55 to +150 |  |

## ESD Ratings (Note 6)

| Characteristic | Symbol | Value | Unit | JEDEC Class |
| :--- | :---: | :---: | :---: | :---: |
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | 13 A |
| Electrostatic Discharge - Machine Model | ESD MM | 400 | V | C |

Notes: $\quad 5$. For a device mounted with the collector lead on minimum recommended pad layout 1oz copper that is on a single-sided 1.6 mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.
6. Refer to JEDEC specification JESD22-A114 and JESD22-A115

Thermal Characteristics and Derating Information


Fig. 1, Max Power Dissipation vs. Ambient Temperature


Fig. 2 Single Pulse Maximum Power Dissipation

BC857AT, BT, CT

## Thermal Characteristics and Derating Information (Cont.)



Electrical Characteristics (@T $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| OFF CHARACTERISTICS (Note 7) |  |  |  |  |  |  |
| Collector-Base Breakdown Voltage | BV CBO | -50 | - | - | V | $\mathrm{I}_{\mathrm{C}}=-100 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{E}}=0$ |
| Collector-Emitter Breakdown Voltage | BV CEO | -45 | - | - | V | $\mathrm{I}_{\mathrm{C}}=-1 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=0$ |
| Emitter-Base Breakdown Voltage | BVEbO | -6 | - | - | V | $\mathrm{I}_{\mathrm{E}}=-100 \mu \mathrm{~A}, \mathrm{I} \mathrm{C}=0$ |
| ON CHARACTERISTICS (Note 7) |  |  |  |  |  |  |
| DC Current Gain Current Gain A <br> B  <br> C  | $h_{\text {FE }}$ | $\begin{aligned} & 125 \\ & 220 \\ & 420 \end{aligned}$ | $\begin{aligned} & \overline{290} \\ & 520 \end{aligned}$ | $\begin{aligned} & 250 \\ & 475 \\ & 800 \end{aligned}$ | - | $V_{C E}=-5 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=-2 \mathrm{~mA}$ |
| Collector-Emitter Saturation Voltage | $\mathrm{V}_{\text {CE(SAT) }}$ | - | - | $\begin{aligned} & \hline-300 \\ & -650 \end{aligned}$ | mV | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=-10 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=-0.5 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{C}}=-100 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=-5 \mathrm{~mA} \end{aligned}$ |
| Base-Emitter Saturation Voltage | $\mathrm{V}_{\mathrm{BE}}(\mathrm{SAT})$ | - | $\begin{array}{r} \hline-700 \\ -900 \\ \hline \end{array}$ | - | mV | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=-10 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=-0.5 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{C}}=-100 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=-5 \mathrm{~mA} \end{aligned}$ |
| Base-Emitter Voltage | $\mathrm{V}_{\mathrm{BE} \text { (ON) }}$ | -600 | - | $\begin{aligned} & \hline-750 \\ & -820 \end{aligned}$ | mV | $\begin{aligned} & \mathrm{V}_{\mathrm{CE}}=-5 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=-2 \mathrm{~mA} \\ & \mathrm{~V}_{\mathrm{CE}}=-5 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=-10 \mathrm{~mA} \end{aligned}$ |
| Collector-Emitter Cutoff Current | Icbo | - | - | $\begin{gathered} -15 \\ -4 \end{gathered}$ | $\begin{aligned} & \mathrm{nA} \\ & \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & V_{C B}=-30 \mathrm{~V} \\ & V_{C B}=-30 \mathrm{~V}, T_{A}=+150^{\circ} \mathrm{C} \end{aligned}$ |
| SMALL SIGNAL CHARACTERISTICS |  |  |  |  |  |  |
| Output Capacitance | COBO | - | - | 4.5 | pF | $\mathrm{V}_{\mathrm{CB}}=-10 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |
| Current Gain-Bandwidth Product | $\mathrm{f}_{\mathrm{T}}$ | 100 | - | - | MHz | $\begin{aligned} & V_{C E}=-5 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=-10 \mathrm{~mA}, \\ & \mathrm{f}=100 \mathrm{MHz} \end{aligned}$ |
| Noise Figure | NF | - | - | 10 | dB | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=-0.2 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=-5 \mathrm{~V}, \\ & \mathrm{R}_{\mathrm{S}}=2 \mathrm{k} \Omega, \mathrm{f}=1 \mathrm{MHz}, \\ & \mathrm{BW}=200 \mathrm{~Hz} \\ & \hline \hline \end{aligned}$ |

Note: $\quad$ 7. Measured under pulsed conditions. Pulse width $\leq 300 \mu \mathrm{~s}$. Duty cycle $\leq 2 \%$.

BC857AT, BT, CT
Typical Electrical Characteristics $\left(@ T_{\mathrm{A}}=+25^{\circ} \mathrm{C}\right.$, unless otherwise specified.)


Fig. 2, Collector Emitter Saturation Voltage vs. Collector Current


Fig. 4, Gain Bandwidth Product vs. Collector Current

$I_{C}$, COLLECTOR CURRENT (mA)
Fig. 3, DC Current Gain vs. Collector Current

BC857AT, BT, CT

## Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.
SOT523


| SOT523 |  |  |  |
| :---: | :---: | :---: | :---: |
| Dim | Min | Max | Typ |
| A | 0.60 | 0.80 | 0.75 |
| A1 | 0.00 | 0.10 | 0.05 |
| A3 | 0.45 | 0.65 | 0.50 |
| b | 0.15 | 0.30 | 0.22 |
| c | 0.10 | 0.20 | 0.12 |
| D | 1.50 | 1.70 | 1.60 |
| E | 1.45 | 1.75 | 1.60 |
| E1 | 0.75 | 0.85 | 0.80 |
| e | 0.50 BSC |  |  |
| e1 | 0.90 | 1.10 | 1.00 |
| L | 0.20 | 0.40 | 0.33 |
| a | $0^{\circ}$ | -- | $8^{\circ}$ |
| All Dimensions in $\mathbf{~ m m}$ |  |  |  |
|  |  |  |  |
|  |  |  |  |

## Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.


| Dimensions | Value |
| :---: | :---: |
| $\mathbf{C}$ | 1.29 |
| $\mathbf{X}$ | 0.40 |
| $\mathbf{X 1}$ | 0.70 |
| $\mathbf{Y}$ | 0.51 |
| $\mathbf{Y 1}$ | 1.80 |

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